

FFSH40120ADN-F085

ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

| Symbol | Parameter | Value | Unit | |
|-----------------------------------|---|--|------|---|
| V _{RRM} | Peak Repetitive Reverse Voltage | 1200 | V | |
| E _{AS} | Single Pulse Avalanche Energy (Note 1) | 210 | mJ | |
| I _F | Continuous Rectified Forward Current @ T _C < 148°C | 20* / 40** | A | |
| | Continuous Rectified Forward Current @ T _C < 135°C | 25* / 50** | | |
| I _{F, Max} | Non-Repetitive Peak Forward Surge Current | T _C = 25°C, 10 μs | 1190 | A |
| | | T _C = 150°C, 10 μs | 990 | A |
| I _{F, SM} | Non-Repetitive Forward Surge Current | Half-Sine Pulse, t _p = 8.3 ms | 135 | A |
| I _{F, RM} | Repetitive Forward Surge Current | Half-Sine Pulse, t _p = 8.3 ms | 74 | A |
| P _{tot} | Power Dissipation | T _C = 25°C | 220 | W |
| | | T _C = 150°C | 37 | W |
| T _J , T _{STG} | Operating and Storage Temperature Range | -55 to +175 | °C | |
| | TO247 Mounting Torque, M3 Screw | 60 | Ncm | |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. E_{AS} of 210 mJ is based on starting T_J = 25°C, L = 0.5 mH, I_{AS} = 29 A, V = 50 V.

*Per leg, ** Per Device

THERMAL CHARACTERISTICS

| Symbol | Parameter | Value | Unit |
|------------------|---|----------------|------|
| R _{θJC} | Thermal Resistance, Junction to Case, Max | 0.68* / 0.34** | °C/W |

*Per leg, ** Per Device

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

| Symbol | Parameter | Test Condition | Min | Typ | Max | Unit |
|----------------|-------------------------|---|-----|------|------|------|
| V _F | Forward Voltage | I _F = 20 A, T _C = 25°C | - | 1.45 | 1.75 | V |
| | | I _F = 20 A, T _C = 125°C | - | 1.7 | 2.0 | |
| | | I _F = 20 A, T _C = 175°C | - | 2.0 | 2.4 | |
| I _R | Reverse Current | V _R = 1200 V, T _C = 25°C | - | - | 200 | μA |
| | | V _R = 1200 V, T _C = 125°C | - | - | 300 | |
| | | V _R = 1200 V, T _C = 175°C | - | - | 400 | |
| Q _C | Total Capacitive Charge | V = 800 V | - | 120 | - | nC |
| C | Total Capacitance | V _R = 1 V, f = 100 kHz | - | 1220 | - | pF |
| | | V _R = 400 V, f = 100 kHz | - | 111 | - | |
| | | V _R = 800 V, f = 100 kHz | - | 88 | - | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

| Part Number | Top Marking | Package | Shipping |
|-------------------|--------------|--|-----------------|
| FFSH40120ADN-F085 | FFSH40120ADN | TO-247-3LD (Pb-Free / Halogen Free) | 30 Units / Tube |

TYPICAL CHARACTERISTICS

($T_J = 25^\circ\text{C}$ unless otherwise noted; per leg)

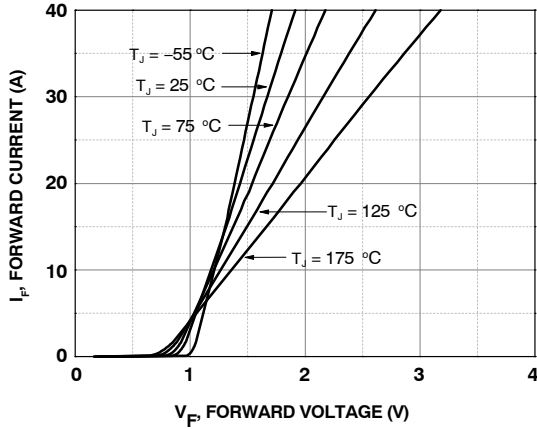


Figure 1. Forward Characteristics

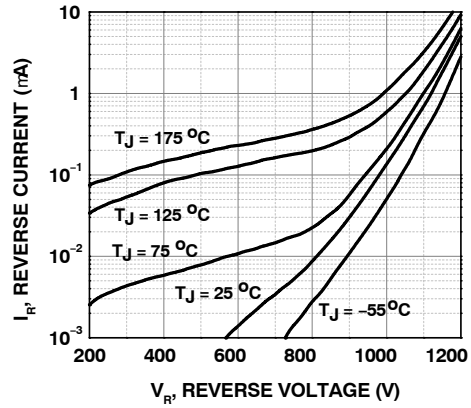


Figure 2. Reverse Characteristics

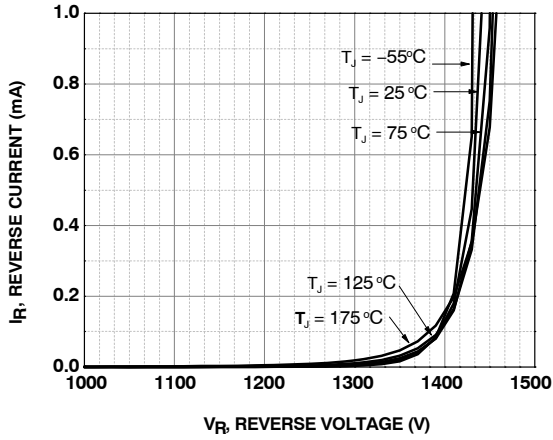


Figure 3. Reverse Characteristics

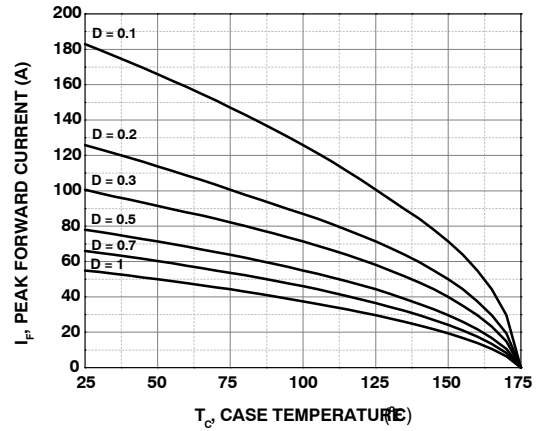


Figure 4. Current Derating

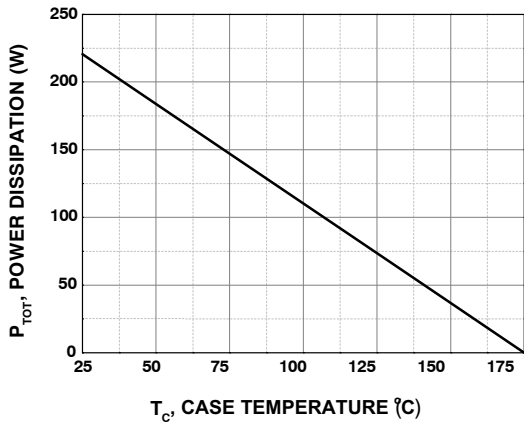


Figure 5. Power Derating

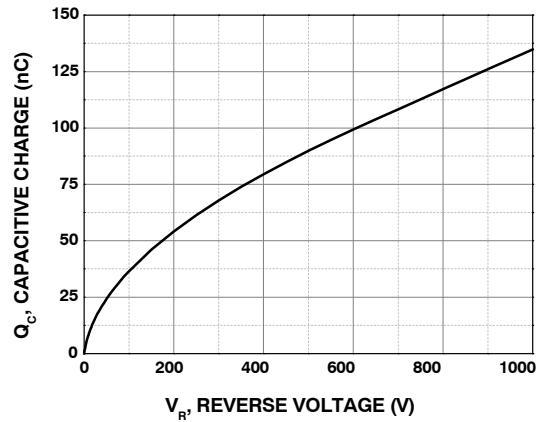


Figure 6. Capacitive Charge vs. Reverse Voltage

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TYPICAL CHARACTERISTICS

($T_J = 25^\circ\text{C}$ unless otherwise noted; per leg; continued)

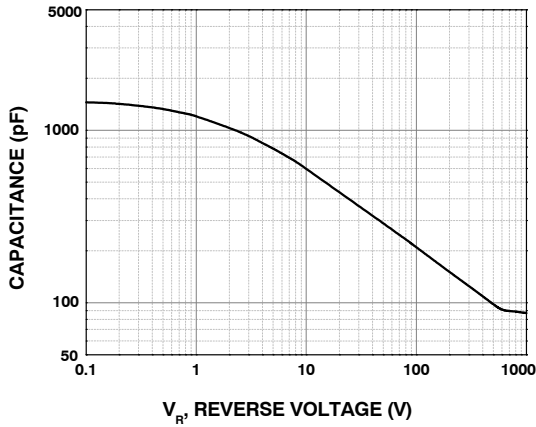


Figure 7. Capacitance vs. Reverse Voltage

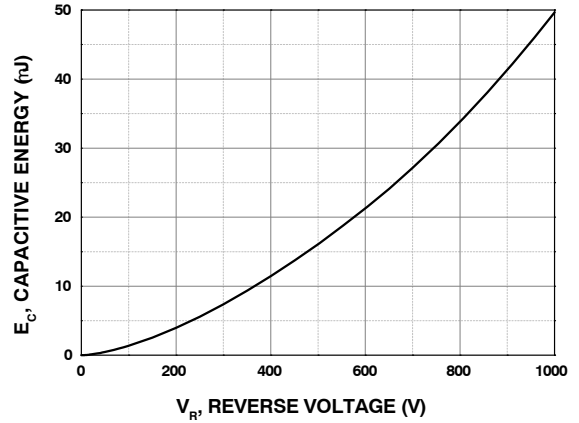


Figure 8. Capacitance Stored Energy

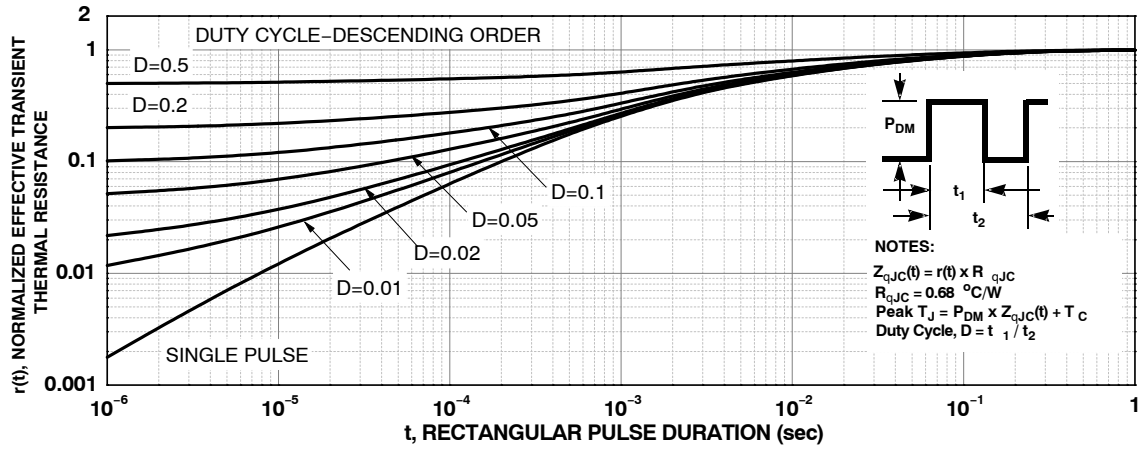


Figure 9. Junction-to-Case Transient Thermal Response Curve

TEST CIRCUIT AND WAVEFORMS

$L = 0.5 \text{ mH}$
 $R < 0.1 \ \Omega$
 $V_{DD} = 50 \text{ V}$
 $E_{AVL} = 1/2LI^2 [V_{R(AVL)} / (V_{R(AVL)} - V_{DD})]$
 $Q1 = \text{IGBT} (BV_{CES} > \text{DUT } V_{R(AVL)})$

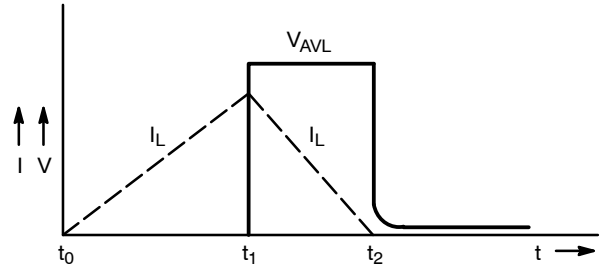
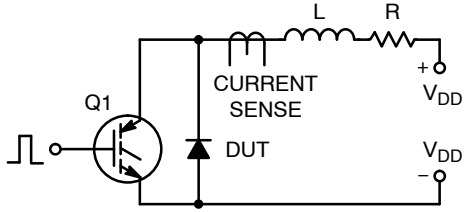


Figure 10. Unclamped Inductive Switching Test Circuit & Waveform

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